

800V Super-junction Power MOSFET

Description

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Super-junction power MOSFET is a revolutionary technology for high voltage power MOSFETs, designed according to the SJ principle and pioneered. The Multi-EPI SJ MOSFET provide an extremely fast and robust body diode. Also provide an extremely low switching, communication and conduction losses device with highest robustness make especially resonant switching applications more reliable, more efficient, lighter and cooler, designed by Wuxi Unigroup Microelectronics Company.

Features		Applications			
Ultra-fast body diode		Switch Mode Pov	wer Supply (SMPS)		
● Very low FOM R _{DS(on)} ×Q _g		Uninterruptible Power Supply (UPS)			
Easy to use/drive		Power Factor Co	rrection (PFC)		
• 100% avalanche tested		LLC Half-bridge			
RoHS compliant		Low Power Chargers and Adapters			
TO-247		Drain			
GDS	Gate Gate Source				
Device Marking and Package	Information		-		
Device	Package		Marking		
TPW80R200MFD	TO-247		80R200MFD		
Key Performance Parameters					
Parameter	Value		Unit		
V _{DS} @ T _{j,max}	850	V			
R _{DS(on),max}	0.2		Ω		
Q _{g,typ}	56.7		nC		
I _D	23		A		
I _{D,pulse}	69		A		
E _{oss} @ 400V	4.9		Lή		
Body Diode di _F /dt	900		A/µs		
t _{rr}	149.5		ns		
Q _{rr}	0.98		μC		
Irrm	11.5		A		



Absolute Maximum Ratings T _c = 25°C, unless otherwise noted						
Parameter			Symbol	Values	Unit	
Continuous Drain Current	T _C = 25°C			23		
	T _C = 100°C		I _D	13.8	A	
Pulsed Drain Current		(note1)	I _{D,pulse}	69	А	
Gate-Source Voltage			V _{GSS}	±30V	V	
Single Pulse Avalanche Energ	у	(note2)	E _{AS}	1125	mJ	
Repetitive Avalanche Energy		(note2)	E _{AR}	27.8	mJ	
Avalanche Current			I _{AR}	4.6	А	
MOSFET dv/dt Ruggedness, \	/ _{DS} = 0480V		dv/dt	50	V/ns	
Power Dissipation For TO-247			P _D	215	W	
Continuous Diode Forward Current			ا _s	23	— A	
Diode Pulsed Current		(note1)	I _{S,pulse}	69		
Reverse Diode dv/dt		(note3)	dv/dt	50	V/ns	
Maximum Diode Commutation Speed		(note3)	di _f /dt	900	A/µs	
Operating Junction and Storag	e Temperature Range		T _J , T _{stg}	-55~+150	°C	

Thermal Resistance For TO-247					
Parameter	Symbol	Value	Unit		
Thermal Resistance, Junction-to-Case	R _{thJC}	0.59	°C/W		
Thermal Resistance, Junction-to-Ambient	R _{thJA}	62.5	-0/00		



Electrical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted						
Demonstern			Value			
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static Characteristics	Static Characteristics					
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0V, I_{D} = 250µA	800			V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 800V, V_{GS} = 0V, T_{J} = 25°C			10	μA
Gate-Source Leakage Current	I _{GSS}	$V_{GS} = \pm 30V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3		5	V
Drain-Source On-State-Resistance	R _{DS(on)}	V_{GS} = 10V , I_D = 11.5A		0.18	0.2	Ω
Gate Resistance	R _G	f = 1.0MHz open drain		1.6		Ω
Dynamic Characteristics						
Input Capacitance	C _{iss}	\/ - 0\/		2441.8		pF
Output Capacitance	C _{oss}	V _{GS} = 0V, V _{DS} = 100V		59.94		
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		4.93		
Total Gate Charge	Qg	V _{DD} = 640V ,		56.7		nC
Gate-Source Charge	Q _{gs}	$I_{\rm D} = 23$ A,		12.2		
Gate-Drain Charge	Q_gd	V_{GS} = 10V		21.4		
Turn-on Delay Time	t _{d(on)}			56.7		ns
Turn-on Rise Time	t _r	$V_{DD} = 400V$		46.2		
Turn-off Delay Time	t _{d(off)}	$I_D = 23A$ $R_G = 25\Omega$		203		
Turn-off Fall Time	t _f			59		
Drain-Source Body Diode Characteristics						
Body Diode Forward Voltage	V_{SD}	$T_J = 25^{\circ}C, I_{SD} = 12A, V_{GS} = 0V$		0.9	1.5	V
Reverse Recovery Time	t _{rr}	V = 400V		149.5		ns
Reverse Recovery Charge	Q _{rr}	$V_R = 400V$ $I_F = 23A$		0.98		μC
Peak Reverse Recovery Current	I _{rrm}	di _F /dt = 100A/µs		11.5		А

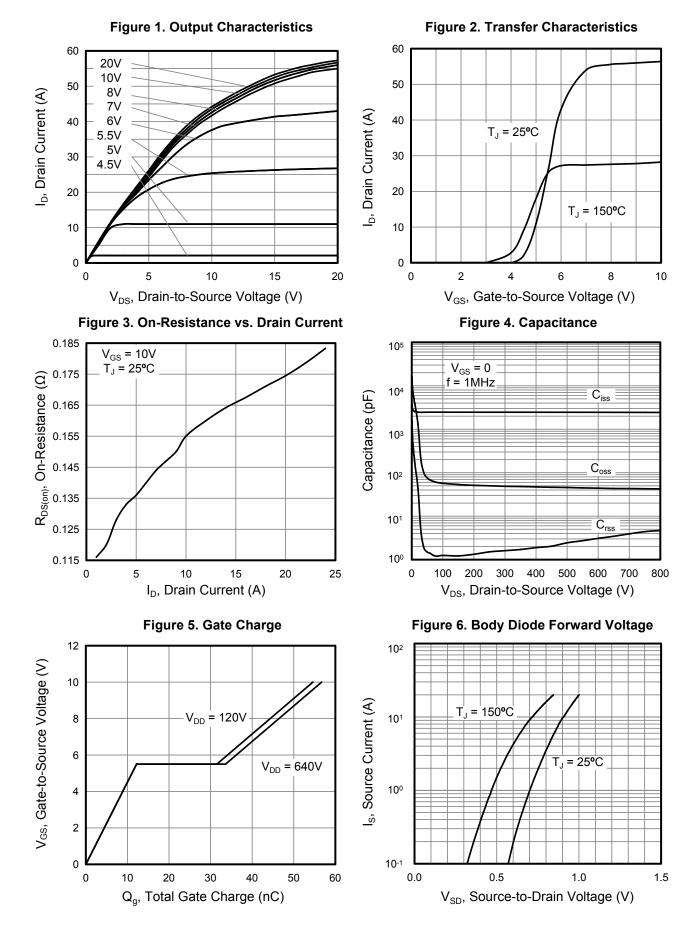
Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. I_D = 10A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C
- 3. Identical low side and high side switch with identical ${\sf R}_{\sf G}$



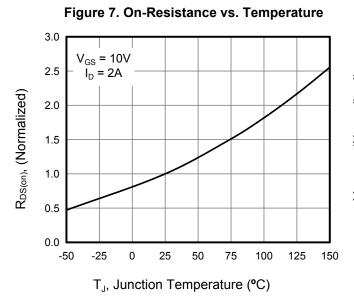


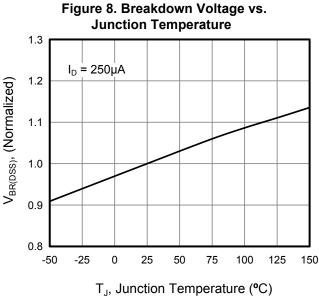
Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted

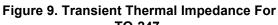


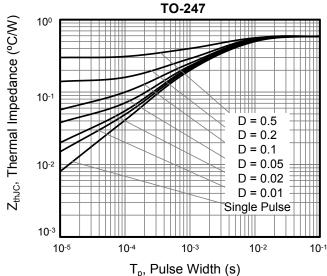


Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted











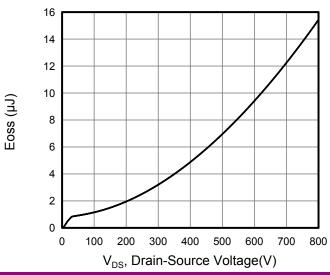
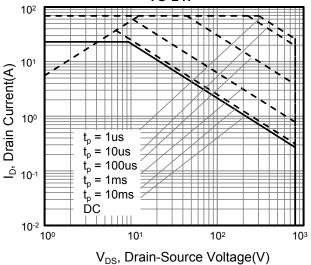


Figure 10. Safe Operation Area For TO-247





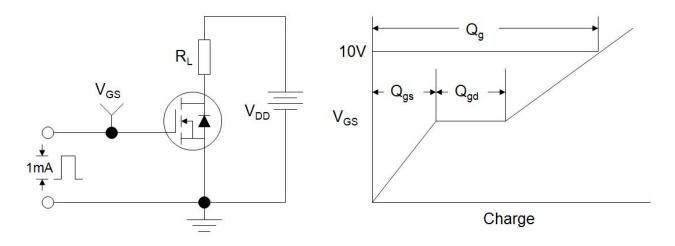


Figure B: Resistive Switching Test Circuit and Waveform

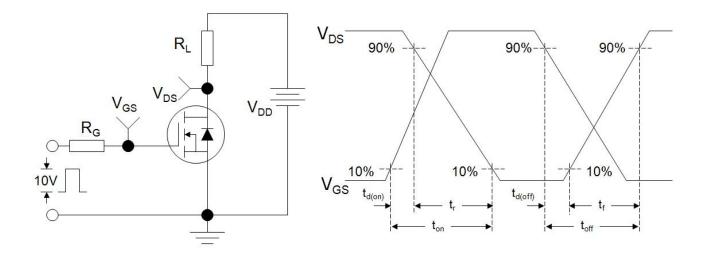
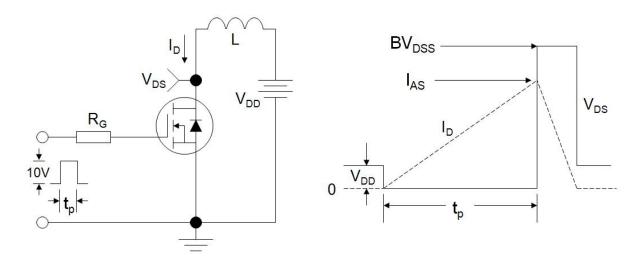


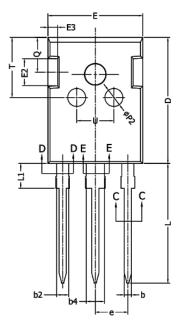
Figure C: Unclamped Inductive Switching Test Circuit and Waveform

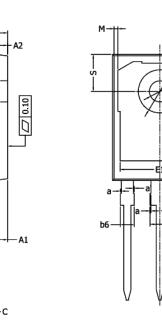




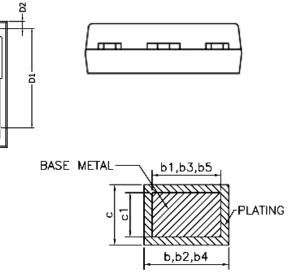


TO-247





h'



SYMBOL	MIN	NOM	MAX	
A	4,90	5.00	5.10	
A1	2.31	2.41	2.51	
A2	1.90	2.00	2.10	
a	0		0.15	
a'	0		0.15	
b	1.16		1.26	
		1.2		
b1	1.15	1.2	1.22	
b2	1.96		2.06	
b3	1.95	2.00	2.02	
b4	2.96		3.06	
b5	2.96	3.00	3.02	
b6			2.25	
b7			3.25	
с	0.59		0.66	
c1	0.58	0.60	0.62	
D	20.90	21.00	21.10	
D1	16.25	16.55	16.85	
D2	1.05	1.17	1.35	
E	15.70	15.80	15.90	
E1	13.10	13.30	13,50	
E2	4.40	4.50	4.60	
E3	2.40	2.50	2.60	
е	5.436 BSC			
L	19.80	19.92	20,10	
L1			4.30	
м	0.35		0.95	
Р	3.40	3.50	3.60	
P1	7.00		7.40	
P2	2,40	2.50	2.60	
Q	5.60		6.00	
S	6.05	6.15	6,25	
Т	9,80		10.20	
U	6,00		6,40	
0	0.00		0,10	



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